MAX207 5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ± 15 -kV ESD PROTECTION

SLLS592B - OCTOBER 2003 - REVISED JANUARY 2004

- ESD Protection for RS-232 I/O Pins - ±15 kV - Human-Body Model
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates at 5-V V_{CC} Supply
- Operates Up To 120 kbit/s
- External Capacitors . . . 4 × 0.1 μF
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- Applications
 - Battery-Powered Systems, PDAs, Notebooks, Laptops, Palmtop PCs, and Hand-Held Equipment

(TOP VIEW) DOUT3 [24 DOUT4 DOUT1 2 23 RIN2 22 ROUT2 DOUT2 3 RIN1 4 21 DIN5 ROUT1 ∏ 5 20 **□** DOUT5 19 **∏** DIN4 DIN2 | 6 DIN1 7 18 DIN3 GND ∏8 17 ROUT3 16 RIN3 V_{CC} [] 9 C1+ 1 10 15 V-V+ **∏** 11 14 ∏ C2-13 C2+

DB OR DW PACKAGE

description/ordering information

The MAX207 consists of five line drivers, three line receivers, and a dual charge-pump circuit with ±15-kV ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 5-V supply. The devices operate at data signaling rates up to 120 kbit/s and a maximum of 30-V/µs driver output slew rate.

ORDERING INFORMATION

TA	PACKAG	GE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	COIC (DW)	Tube of 25	MAX207CDW	MA V0070
0°C to 70°C	SOIC (DW)	Reel of 2000	MAX207CDWR	MAX207C
	SSOP (DB)	Reel of 2000	MAX207CDBR	MA207C
	0010 (DW)	Tube of 25	MAX207IDW	MAN VOOZI
-40°C to 85°C	SOIC (DW)	Reel of 2000	MAX207IDWR	MAX207I
	SSOP (DB)	Reel of 2000	MAX207IDBR	MB207I

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



Function Tables

EACH DRIVER

INPUT D _{IN}	OUTPUT DOUT
L	Н
Н	L

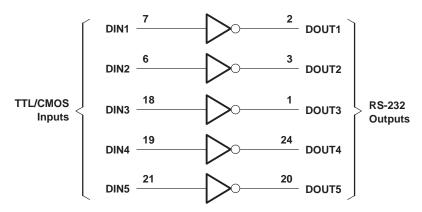
H = high level, L = low level

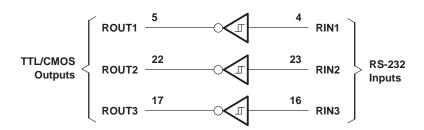
EACH RECEIVER

INPUT R _{IN}	OUTPUT ROUT
L	Н
Н	L
Open	Н

H = high level, L = low level, Open = input disconnected or connected driver off

logic diagram (positive logic)







absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC} (see Note 1)	0.3 V to 6 V
Positive charge pump voltage range, V+ (see Note 1)	
Negative charge pump voltage range, V- (see Note 1)	–14 V to 0.3 V
Input voltage range, V _I : Drivers	0.3 V to V+ + 0.3 V
Receivers	±30 V
Output voltage range, V _O : Drivers	V– – 0.3 V to V+ + 0.3 V
Receivers	0.3 V to V _{CC} + 0.3 V
Short-circuit duration: DOUT	Continuous
Package thermal impedance, θ_{JA} (see Notes 2 and 3): DI	B package 63°C/W
DI	W package 46°C/W
Operating virtual junction temperature, T _J	
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to network GND.
 - 2. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
 - 3. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 4 and Figure 4)

			MIN	NOM	MAX	UNIT
	Supply voltage		4.5	5	5.5	V
VIH	Driver high-level input voltage	D _{IN}	2			V
VIL	Driver low-level input voltage	D _{IN}			8.0	V
.,	Driver input voltage	D _{IN}	0		5.5	
VI	Receiver input voltage		-30		30	V
т.		MAX207C	0		70	00
TA	Operating free-air temperature	MAX207I	-40		85	°C

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V \pm 0.5 V.

electrical characteristics over recommended ranges of supply voltage (unless otherwise noted) (see Note 4 and Figure 4)

	PARAMETER		TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
ICC	Supply current	No load,	V _{CC} = 5 V,	T _A = 25°C		11	20	mA

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V \pm 0.5 V.



DRIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 4)

PARAMETER		TEST CONDITIONS			TYP†	MAX	UNIT
Vон	High-level output voltage	D _{OUT} at R _L = 3 k Ω to GND,	$D_{IN} = GND$	5	9		V
VOL	Low-level output voltage	D _{OUT} at R _L = 3 k Ω to GND,	DIN = VCC	-5	-9		V
lн	High-level input current	VI = VCC			15	200	μΑ
IIL	Low-level input current	V _I at 0 V			-15	-200	μΑ
los [‡]	Short-circuit output current	V _{CC} = 5.5 V,	V _O = 0 V		±10	±60	mA
r _O	Output resistance	V_{CC} , V+, and V- = 0 V,	V _O = ±2 V	300			Ω

[†] All typical values are at $V_{CC} = 5 \text{ V}$, and $T_A = 25^{\circ}\text{C}$.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 4)

PARAMETER		ER TEST CONDITIONS			TYP	MAX	UNIT
	Maximum data rate	C _L = 50 to 1000 pF, One D _{OUT} switching,	R _L = 3 k Ω to 7 k Ω , See Figure 1	120			kbit/s
^t PLH (D)	Propagation delay time, low- to high-level output	C _L = 2500 pF, all drivers loaded,	$R_L = 3 kΩ$, See Figure 1		2		μs
^t PHL (D)	Propagation delay time, high- to low-level output	C _L = 2500 pF, all drivers loaded,	$R_L = 3 kΩ$, See Figure 1		2		μs
tsk(p)	Pulse skew§	$C_L = 150 \text{ pF to } 2500 \text{ pF},$	R _L = 3 kΩ to 7 kΩ, See Figure 2		300		ns
SR(tr)	Slew rate, transition region (see Figure 1)	C _L = 50 pF to 1000 pF V _{CC} = 5 V	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$	3	6	30	V/μs

[†] All typical values are at $V_{CC} = 5 \text{ V}$, and $T_A = 25^{\circ}\text{C}$.

ESD protection

PIN	TEST CONDITIONS	TYP	UNIT
D _{OUT} , R _{IN}	Human-Body Model	±15	kV



^{\$} Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V \pm 0.5 V.

 $[\]mbox{\$ Pulse skew is defined as } \mbox{$tp_{LH}-t_{PHL}$} \mbox{ of each channel of the same device.} \label{eq:pulse skew}$ NOTE 4: Test conditions are C1–C4 = 0.1 μF at V_CC = 5 V \pm 0.5 V.

RECEIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 4)

	PARAMETER	TEST COND	ITIONS	MIN	TYP [†]	MAX	UNIT
Vон	High-level output voltage	I _{OH} = -1 mA		3.5	V _{CC} -0.4 V		V
VOL	Low-level output voltage	I _{OL} = 1.6 mA				0.4	V
V _{IT+}	Positive-going input threshold voltage	$V_{CC} = 5 V$,	T _A = 25°C		1.7	2.4	V
VIT-	Negative-going input threshold voltage	$V_{CC} = 5 V$,	T _A = 25°C	0.8	1.2		V
V _{hys}	Input hysteresis (V _{IT+} - V _{IT-})			0.2	0.5	1	V
rį	Input resistance	$V_I = \pm 3 \text{ V to } \pm 25 \text{ V}$		3	5	7	kΩ

[†] All typical values are at $V_{CC} = 5$ V, and $T_A = 25$ °C.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V \pm 0.5 V.

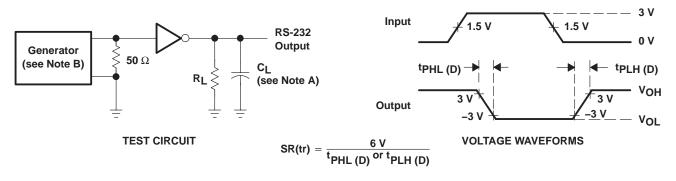
switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 4 and Figure 3)

	PARAMETER	TEST CONDITIONS	MIN	TYP [†]	MAX	UNIT
tPLH	Propagation delay time, low- to high-level output	0 450 = 5		0.5	10	μs
tPHL	Propagation delay time, high- to low-level output	C _L = 150 pF		0.5	10	μs
tsk(p)	Pulse skew [‡]			300		ns

[†] All typical values are at V_{CC} = 5 V, and T_A = 25°C.

NOTE 4: Test conditions are C1–C4 = 0.1 μ F, at V_{CC} = 5 V \pm 0.5 V.

PARAMETER MEASUREMENT INFORMATION



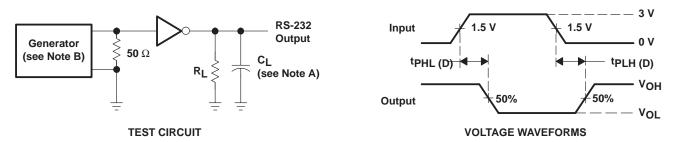
NOTES: A. CL includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 120 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns. $t_f \le 10$ ns.

Figure 1. Driver Slew Rate

[‡] Pulse skew is defined as |tpLH - tpHL| of each channel of the same device.

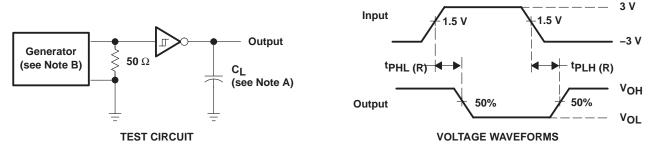
PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 120 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_\Gamma \le 10$ ns. $t_f \le 10$ ns.

Figure 2. Driver Pulse Skew



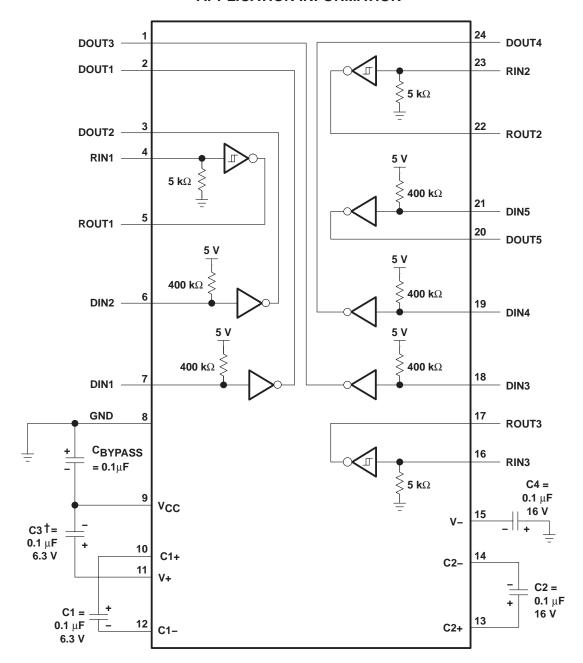
NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $Z_O = 50~\Omega$, 50% duty cycle, $t_\Gamma \le 10~\text{ns}$.

Figure 3. Receiver Propagation Delay Times



APPLICATION INFORMATION



 $\ensuremath{^\dagger\text{C3}}$ can be connected to $\ensuremath{^{V_{CC}}}$ or GND.

NOTES: A. Resistor values shown are nominal.

B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

Figure 4. Typical Operating Circuit and Capacitor Values



APPLICATION INFORMATION

capacitor selection

The capacitor type used for C1–C4 is not critical for proper operation. The MAX207 requires 0.1- μ F capacitors, although capacitors up to 10 μ F can be used without harm. Ceramic dielectrics are suggested for the 0.1- μ F capacitors. When using the minimum recommended capacitor values, make sure the capacitance value does not degrade excessively as the operating temperature varies. If in doubt, use capacitors with a larger (e.g., 2×) nominal value. The capacitors' effective series resistance (ESR), which usually rises at low temperatures, influences the amount of ripple on V+ and V-.

Use larger capacitors (up to 10 μF) to reduce the output impedance at V+ and V-.

Bypass V_{CC} to ground with at least 0.1 μ F. In applications sensitive to power-supply noise generated by the charge pumps, decouple V_{CC} to ground with a capacitor the same size as (or larger than) the charge-pump capacitors (C1–C4).

ESD protection

TI MAX207 devices have standard ESD protection structures incorporated on the pins to protect against electrostatic discharges encountered during assembly and handling. In addition, the RS232 bus pins (driver outputs and receiver inputs) of these devices have an extra level of ESD protection. Advanced ESD structures were designed to successfully protect these bus pins against ESD discharge of ±15-kV when powered down.

ESD test conditions

ESD testing is stringently performed by TI, based on various conditions and procedures. Please contact TI for a reliability report that documents test setup, methodology, and results.

Human-Body Model

The Human-Body Model (HBM) of ESD testing is shown in Figure 5, while Figure 6 shows the current waveform that is generated during a discharge into a low impedance. The model consists of a 100-pF capacitor, charged to the ESD voltage of concern, and subsequently discharged into the device under test (DUT) through a 1.5-k Ω resistor.

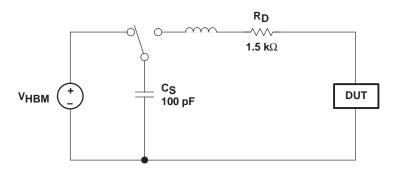


Figure 5. HBM ESD Test Circuit



APPLICATION INFORMATION

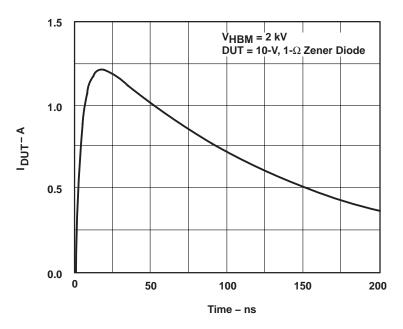


Figure 6. Typical HBM Current Waveform

Machine Model

The Machine Model (MM) ESD test applies to all pins using a 200-pF capacitor with no discharge resistance. The purpose of the MM test is to simulate possible ESD conditions that can occur during the handling and assembly processes of manufacturing. In this case, ESD protection is required for all pins, not just RS-232 pins. However, after PC board assembly, the MM test no longer is as pertinent to the RS-232 pins.



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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(0)
MAX207CDB	Obsolete	Production	SSOP (DB) 24	-	-	Call TI	Call TI	0 to 70	MA207C
MAX207CDBR	Active	Production	SSOP (DB) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	MA207C
MAX207CDBR.A	Active	Production	SSOP (DB) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	MA207C
MAX207CDW	Obsolete	Production	SOIC (DW) 24	-	-	Call TI	Call TI	0 to 70	MAX207C
MAX207CDWR	Obsolete	Production	SOIC (DW) 24	-	-	Call TI	Call TI	0 to 70	MAX207C
MAX207IDBR	Active	Production	SSOP (DB) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB207I
MAX207IDBR.A	Active	Production	SSOP (DB) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MB207I
MAX207IDW	Obsolete	Production	SOIC (DW) 24	-	-	Call TI	Call TI	-40 to 85	MAX207I
MAX207IDWR	Active	Production	SOIC (DW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MAX207I
MAX207IDWR.A	Active	Production	SOIC (DW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MAX207I

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

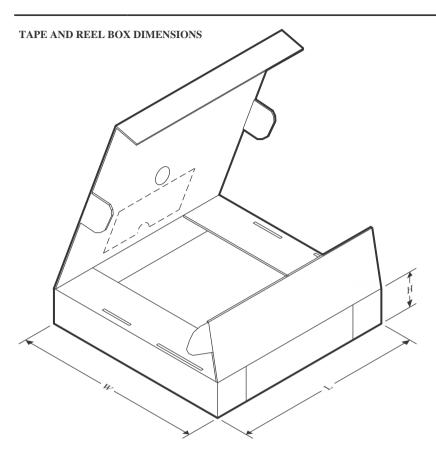
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MAX207CDBR	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1
MAX207IDBR	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1
MAX207IDWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MAX207CDBR	SSOP	DB	24	2000	353.0	353.0	32.0
MAX207IDBR	SSOP	DB	24	2000	353.0	353.0	32.0
MAX207IDWR	SOIC	DW	24	2000	350.0	350.0	43.0

DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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